NSN 5961-00-923-0778



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-923-0778 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case: Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 35.0 breakdown voltage, collector-to-emitter, base open and 20.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 386.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Reference Number Differentiating Characteristics:** Quality controlled in accordance with mil-q-9858 Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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